



SPECIFICATION

• Supplier : Samsung electro-mechanics • Samsung P/N : CL32A106KAILNNE

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 10 µF, 25V, ±10%, X5R, 1210

A. Samsung Part Number

<u>CL</u> <u>32</u> <u>A</u> <u>106</u> <u>K</u> <u>A</u> <u>I</u> <u>L</u> <u>N</u> <u>N</u> <u>E</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

① Series	Samsung Multi-layer Ceramic Capacitor				
② Size	1210 (inch code)	L: 3.2 ± 0.3	mm W	2.5 ± 0.2	mm
		Thic	Thickness division Low profile		
3 Dielectric	X5R	Inne	r electrode	Ni	
4 Capacitance	10 μF	Term	nination	Cu	
⑤ Capacitance	±10 %	Plati	ng	Sn 100%	(Pb Free)
tolerance		Prod	uct	Normal	
Rated Voltage	25 V	® Spec	ial	Reserved for	future use
Thickness	2.0 ± 0.2 mm	① Pack	aging	Embossed T	ype, 7" reel

B. Samsung Reliablility Test and Judgement condition

	Performance	Test condition			
Capacitance	Within specified tolerance	1kHz±10% 1.0±0.2 Vrms			
Tan δ (DF)	0.1 max.				
Insulation	10,000Mohm or 100Mohm⋅ <i>μ</i> F	Rated Voltage 60~120 sec.			
Resistance	Whichever is Smaller				
Appearance	No abnormal exterior appearance	Microscope (×10)			
Withstanding	No dielectric breakdown or	250% of the rated voltage			
Voltage	mechanical breakdown				
Temperature	X5R				
Characterisitcs	(From -55 ℃ to 85 ℃, Capacitance change shoud be within ±15%)				
Adhesive Strength	No peeling shall be occur on the	500g⋅F, for 10±1 sec.			
of Termination	terminal electrode				
Bending Strength	Capacitance change : within ±12.5%	Bending to the limit (1mm)			
		with 1.0mm/sec.			
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder			
	is to be soldered newly	245±5℃, 3±0.3sec.			
		(preheating : 80~120℃ for 10~30sec.)			
Resistance to	Capacitance change: within ±7.5%	Solder pot : 270±5℃, 10±1sec.			
Soldering heat	Tan δ, IR : initial spec.				

	Performance	Test condition		
Vibration Test	Capacitance change : within ±5%	Amplitude : 1.5mm		
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)		
		2hours \times 3 direction (x, y, z)		
Moisture	Capacitance change : within ±12.5%	With rated voltage		
Resistance	Tan δ: 0.125 max	40±2℃, 90~95%RH, 500+12/-0hrs		
	IR : 12.5MΩ·μF or Over			
High Temperature	Capacitance change: within ±12.5%	With 150% of the rated voltage		
Resistance	Tan δ: 0.125 max	Max. operating temperature		
	IR : 25MΩ·μF or Over			
		1000+48/-0hrs		
Temperature	Capacitance change : within ±7.5%	1 cycle condition		
Cycling	Tan δ, IR : initial spec.	Min. operating temperatur → 25°C		
		→ Max. operating temperature → 25°C		
		5 cycle test		

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}$ C, 10sec. Max)

^{*} For the more detail Specification, Please refer to the Samsung MLCC catalogue.